



General Specifications

Resistive Element:	Thick film
Substrate:	Aluminum nitride ceramic
Cover:	Alumina ceramic
Lead(s):	99.99% pure silver (.005" thk)

Electrical Specifications

Resistance Value:	50 ohms, $\pm 5\%$
Frequency Range:	DC - 4.0 GHz
Power:	30 Watts
V.S.W.R.:	1.25:1

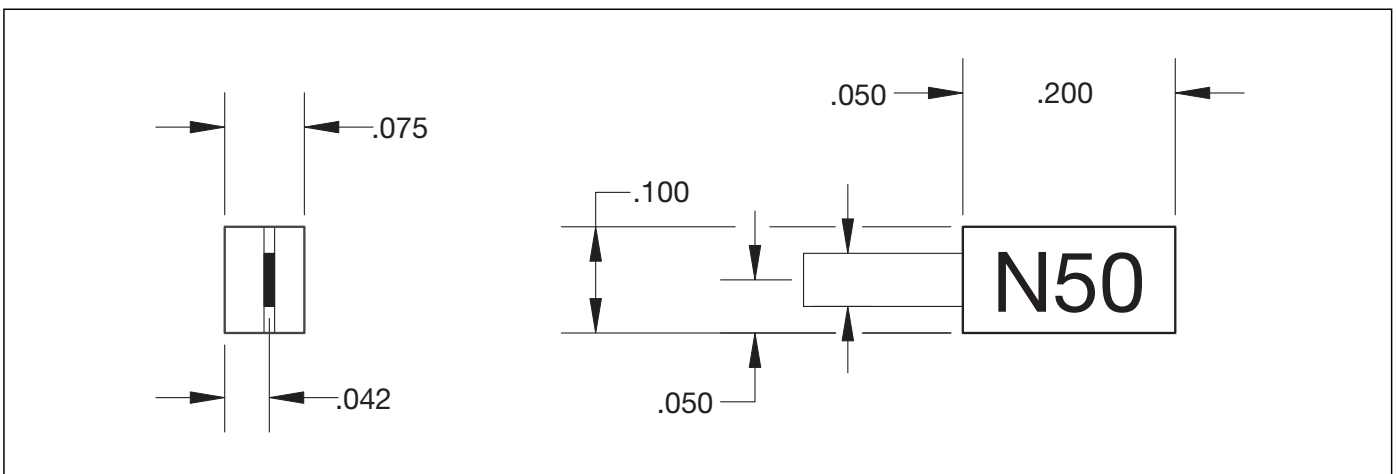
Notes: Tolerance is ± 0.010 , unless otherwise specified. Operating temperature is -55°C to $+150^{\circ}\text{C}$ (see chart). Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions are in inches. Lead length 0.15" minimum.

Specifications subject to change without notice.

Features

- DC – 4.0 GHz
- 30 Watts
- Aluminum Nitride (AlN) Ceramic
- Welded Silver Leads
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Outline Drawing



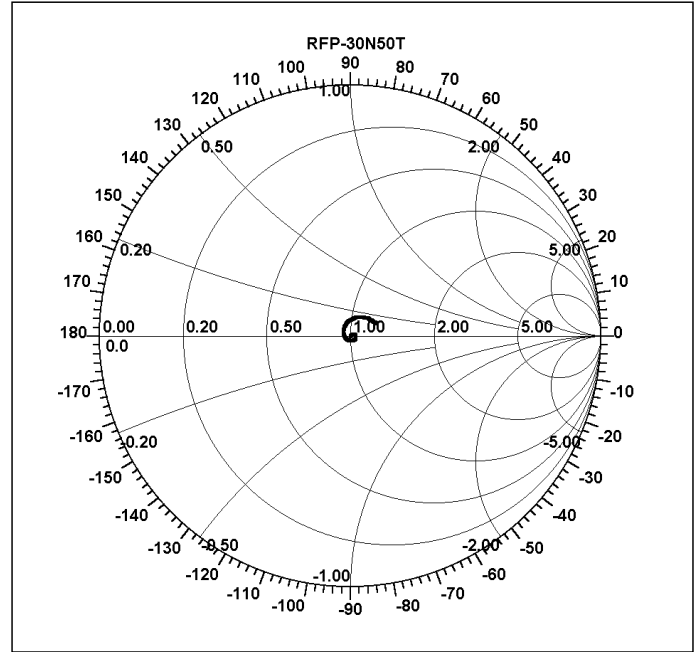
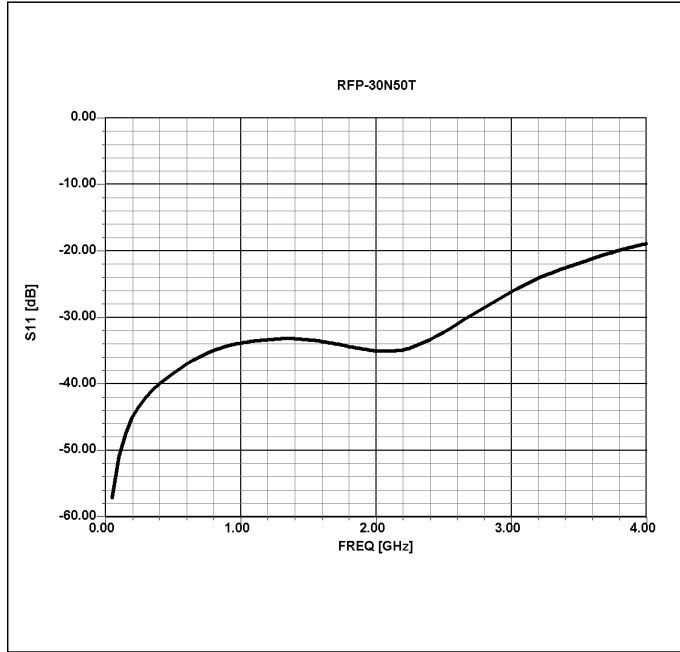
VER. 12/5/01

Model RFP-30N50T

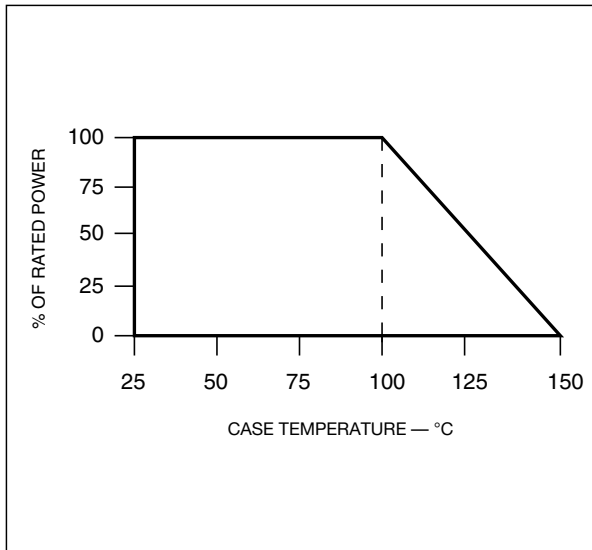


RF Power

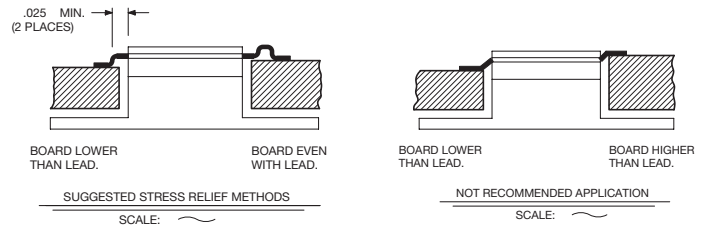
Typical Performance



Power Derating



Suggested Mounting Procedures



1. Make sure that the devices are mounted on flat surfaces (.001" under the device) to optimize the heat transfer.
2. Position device on mounting surface and solder in place using an SN96 type solder.
3. Solder leads in place using an SN63 type solder with a controlled temperature iron (700°F).